# NSN 5962-01-353-1618

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## Body Length:

1.290 inches

## **Body Width:**

Between 0.500 inches and 0.610 inches

## **Body Height:**

0.210 inches

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

### **Features Provided:**

Hermetically sealed and burn in and w/enable and programmed and electrostatic sensitive

### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

#### Input Circuit Pattern:

14 input

## **Current Rating Per Characteristic:**

185.00 milliamperes reverse current, dc absolute

## **Terminal Surface Treatment:**

Solder

### Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

### **Capitance Rating Per Characteristic:**

10.00 input pascal industrial light tank stock and 15.00 output pascal industrial light tank stock

### Time Rating Per Chacteristic:

70.00 nanoseconds access

#### Memory Device Type:

Prom

# Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# Terminal Type And Quantity:

24 printed circuit

# Shelf Life:

N/a

# Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

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